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# 2SB1403

Silicon PNP Triple Diffused

## HITACHI

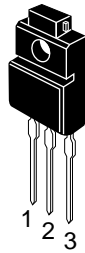
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### Application

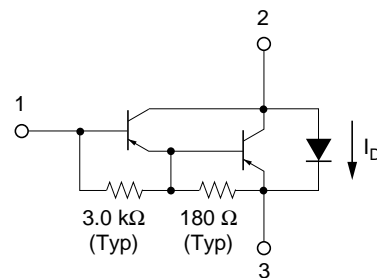
Low frequency power amplifier

### Outline

TO-220FM



- 1. Base
- 2. Collector
- 3. Emitter



## 2SB1403

### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	-120	V
Collector to emitter voltage	$V_{CEO}$	-120	V
Emitter to base voltage	$V_{EBO}$	-7	V
Collector current	$I_C$	-6	A
Collector peak current	$I_{C(\text{peak})}$	-12	A
Collector power dissipation	$P_C$	2	W
	$P_C^{*1}$	25	
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{\text{stg}}$	-55 to +150	°C
C to E diode forward current	$I_D^{*1}$	6	A

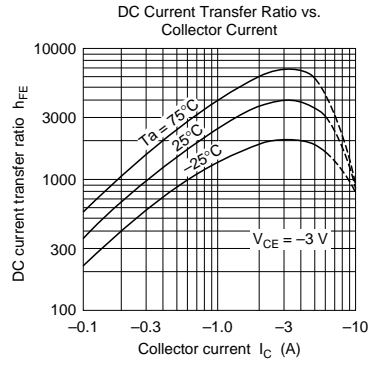
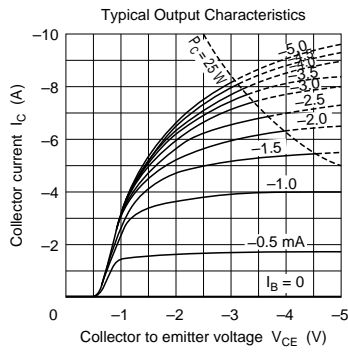
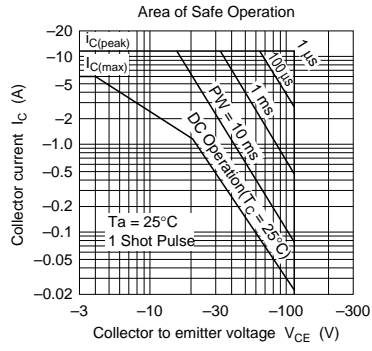
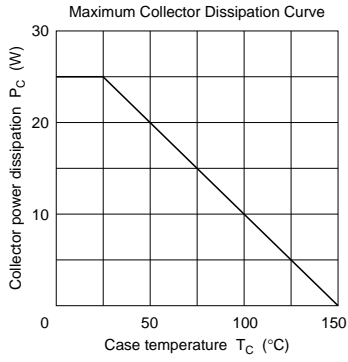
Note: 1. Value at  $T_c = 25^\circ\text{C}$ .

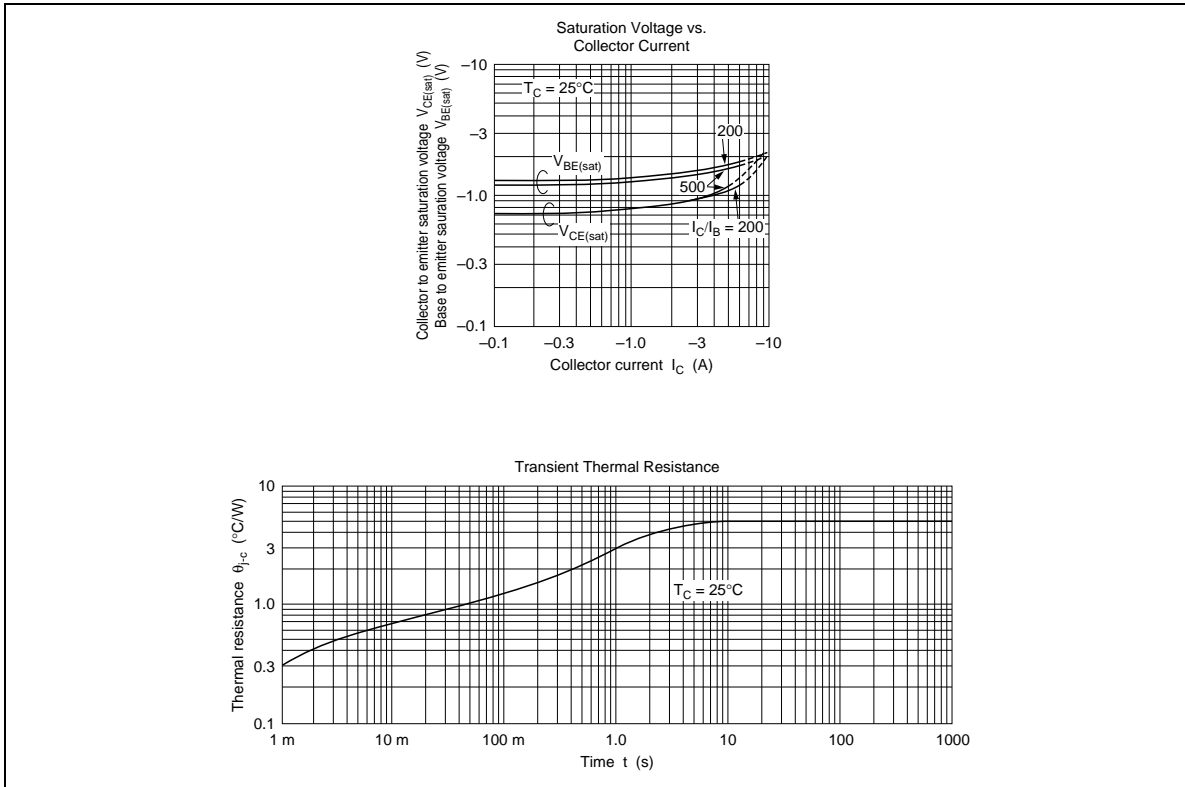
### Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-120	—	—	V	$I_C = -0.1 \text{ mA}$ , $I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-120	—	—	V	$I_C = -25 \text{ mA}$ , $R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-7	—	—	V	$I_E = -50 \text{ mA}$ , $I_C = 0$
Collector cutoff current	$I_{CBO}$	—	—	-10	$\mu\text{A}$	$V_{CB} = -100 \text{ V}$ , $I_E = 0$
	$I_{CEO}$	—	—	-10		$V_{CE} = -100 \text{ V}$ , $R_{BE} = \infty$
DC current transfer ratio	$h_{FE}$	1000	—	20000		$V_{CE} = -3 \text{ V}$ , $I_C = -3 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{CE(\text{sat})1}$	—	—	-1.5	V	$I_C = -3 \text{ A}$ , $I_B = -6 \text{ mA}^{*1}$
	$V_{CE(\text{sat})2}$	—	—	-3.0		$I_C = -6 \text{ A}$ , $I_B = -60 \text{ mA}^{*1}$
Base to emitter saturation voltage	$V_{BE(\text{sat})1}$	—	—	-2.0	V	$I_C = -3 \text{ A}$ , $I_B = -6 \text{ mA}^{*1}$
	$V_{BE(\text{sat})2}$	—	—	-3.5		$I_C = -6 \text{ A}$ , $I_B = -60 \text{ mA}^{*1}$
C to E diode forward voltage	$V_D$	—	—	3.0	V	$I_D = 6 \text{ A}^{*1}$

Note: 1. Pulse test.

See switching characteristic curve of 2SB1106.





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